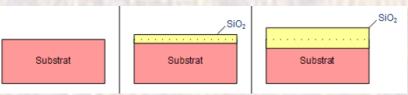
## Oxidation

## Last updated 3/5/19

## Oxidation

- Oxidation
  - The conversion of Si to Si0<sub>2</sub>
    - SiO<sub>2</sub> used as an insulator in semiconductors
    - Some of the Si is consumed in the process
    - SiO<sub>2</sub> is less dense than Si
    - Performed at high temp (1000 °C)
  - Dry Oxidation
    Si + O<sub>2</sub> <-> SiO<sub>2</sub>
  - Wet Oxidation
    Si + 2H<sub>2</sub>O <-> SiO<sub>2</sub> + 2H



Growth: 54% above original surface 46% below original surface

## Oxidation

- Oxidation
  - Si oxidizes at room temperature
    - A few atomic layers worth of SiO<sub>2</sub> form naturally (skin)
    - Wafer processing requires regular etching of this thin layer whenever direct access to the Si is desired

